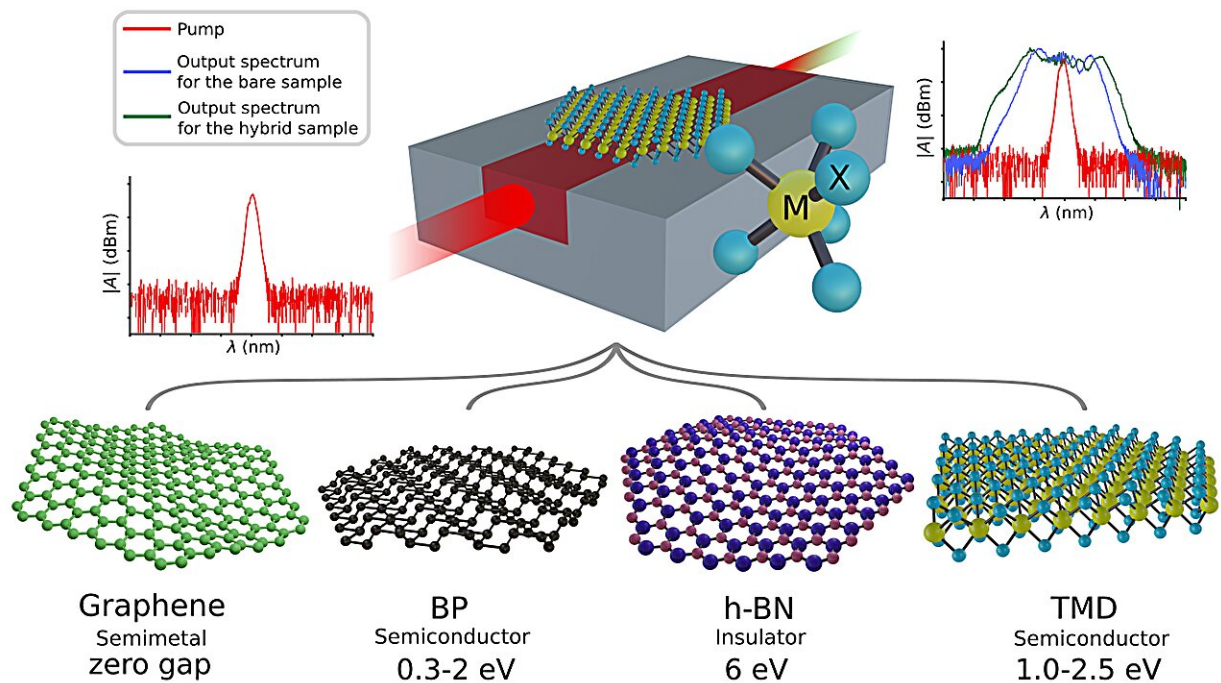


# Integrating 2D materials for on-chip photonics

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Conceptual representation of the hybrid integration of 2D materials. Below are lists of the most common 2D materials with their bandgaps that have been integrated with waveguide structures. The inset spectra show the input (red) spectrum, and the output broadened spectra (blue for intrinsic waveguides and green for the 2D material integrated waveguides) during a typical pulse broadening experiment. Credit: Vincent Pelgrin, Yoon Hoon Hahn, Eric Cassan, and Zhipei Sun

Recently, the introduction of nonlinear optical functions in integrated optics has sparked significant enthusiasm. Demonstrations have shown the potential for integrated photonic platforms. Furthermore, large-scale manufacturing capability and affordability have motivated the development of fully integrated, nonlinear optical devices, aiming at various applications, such as all on-chip spectroscopy, on-chip quantum computations and communications, efficient multiplexing for data communications, on-chip metrology, bio-sensing, or LIDARs.

In a paper published in *Light: Advanced Manufacturing*, a team of scientists led by Professors Vincent Pelgrin and Zhipei Sun reviewed the range of hybrid photonic integration structures.

Integrating these different active functions in [silicon photonics](#) has attracted much attention. The possible compatibility with CMOS processes and the overall low cost of the platform make it very attractive to the industry, with devices directly suitable for dense optical circuit fabrication.

These deep integration capabilities make the Si-compatible platform an interesting testbed for the transposition. Silicon photonics presents some impediments when considering the exploitation of nonlinear optical processes. These are primarily the weak nonlinear responses of the most common materials compatible with its clean room processes or to the presence of free carriers.

Si is highly nonlinear in the C-band range but suffers from two photons absorption (TPA) due to its low bandgap. Unfortunately, most classical materials compatible with silicon integration lack strength in terms of optical nonlinearities. The stoichiometric SiN nonlinear refractive index ( $n_2$ ) is almost two orders of magnitude lower than Si. The stoichiometric SiN nonlinear refractive index ( $n_2$ ) is nearly two orders of magnitude lower than Si.

Impressive demonstrations have been presented using various silicon-based materials to generate integrated optical functions. These include supercontinuum sources, frequency combs, and photon pair sources through spontaneous four-wave mixing. In some fields, the communities have pushed for more efficient devices showing [high performance](#) with low power consumption.

Annealed SiN waveguides with loss levels of a few dB/m have been demonstrated, but the needed pump power was still large. Long waveguides were required to achieve sufficient nonlinear processes, thus making optical functions demanding for fully integrated devices.

Alternatively, materials such as Si-rich waveguides or using p-i-n junctions to engineer carrier density have shown some promising results. However, there are some drawbacks. Si-rich waveguides still present TPA. At the same time, using multiple p-i-n junctions adds another layer of complexity to devices and circuits. Hence, the need for solutions to this limitation is still strong.

Another approach is to introduce highly nonlinear materials to the on-chip platform to take advantage of the highly effective properties of these materials. This approach boosts their nonlinear performance via the integration strategy. Several materials have been tested throughout the past decade.

Chalcogenides are a popular alternative to Si-based materials. In the quest to identify disrupting nonlinear optical materials, two-dimensional (2-D) layered materials have been identified as extremely promising. These materials have third-order susceptibility up to two orders of magnitude higher than Si.

The most widely known material in this category is graphene. Still, other 2-D materials such as transition metal dichalcogenide (TMDs). The  $\text{MX}_2$

crystals are where M stands for a metal atom and X for a chalcogen). BP is also receiving increasing attention. The principle behind hybrid integration consists in incorporating high-performance 2-D materials into the existing integration platforms, thus increasing the overall effective nonlinear performance of the waveguides.

Several challenges arise from the hybrid integration approach, as 2-D materials are still not fully understood. The impact of their addition to integrated structures needs to be handled carefully.

The review presents recent progress in the field and the team's perspectives. They briefly introduced the theoretical background of the hybrid [integration](#) of 2-D materials for the different integrated optics platforms. The aim is to describe key steps, from the modeling and the design to the characterization steps. This will hopefully serve as a guideline for future works on the related fields, thus solving one of the obstacles met with integrated nonlinear photonics.

**More information:** Vincent Pelgrin et al, Hybrid integration of 2D materials for on-chip nonlinear photonics, *Light: Advanced Manufacturing* (2023). [DOI: 10.37188/lam.2023.014](https://doi.org/10.37188/lam.2023.014)

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